

**EAST - [10830119.wsp:1]**

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S1: (5360) (magnetic adj random adj access adj memory "MRAM")  
S2: (1264) S1 and (magnetic near tunneling near junction "MTJ")  
S3: (4) S2 and (lower near magnetic and upper near magnetic and tunnel\$3 near oxide  
S4: (24) S2 and (lower near magnetic and upper near magnetic)  
S5: (10) S2 and (oxidation near prevent\$3)  
S6: (2) S1 and (oxidation near prevent\$3 and tunneling near oxide)  
S7: (68) S1 and (oxidation near prevent\$3)  
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Default operator: OR Highlight all hit terms initially

1 and (oxidation near prevent\$3)

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	U	1	Document ID	Issue Date	Pages	Title	Current OR	Current XRef
1	<input type="checkbox"/>	<input type="checkbox"/>	US 20050186686 A1	20050825	54	METHOD OF FABRICATING DATA TRACKS FOR USE IN A MAGNETIC SHIFT REGISTER MEMORY DEVICE	438/3	
2	<input type="checkbox"/>	<input type="checkbox"/>	US 20050185435 A1	20050825	21	Magnetic storage device and method of fabricating the same	365/36	
3	<input type="checkbox"/>	<input type="checkbox"/>	US 20050174861 A1	20050811	31	Phase-change memory device and method of manufacturing the same	365/200	
4	<input type="checkbox"/>	<input type="checkbox"/>	US 20050169047 A1	20050804	20	Magnetic field sensor using spin polarized current	365/158	
5	<input type="checkbox"/>	<input type="checkbox"/>	US 20050162970 A1	20050728	67	Magnetic memory device and manufacturing method thereof	365/232	
6	<input type="checkbox"/>	<input type="checkbox"/>	US 20050062076 A1	20050324	14	Method of manufacturing magnetic memory device, and magnetic memory device	257/222	
7	<input type="checkbox"/>	<input type="checkbox"/>	US 20050052938 A1	20050310	42	Magnetic memory device and method of manufacturing the same	365/232	
8	<input type="checkbox"/>	<input type="checkbox"/>	US 20050048674 A1	20050303	15	Method and system for providing a magnetic element including passivation structures	438/3	
9	<input type="checkbox"/>	<input type="checkbox"/>	US 20050047204 A1	20050303	20	Ferromagnetic layer compositions and structures for spin polarized memory device	365/158	
10	<input type="checkbox"/>	<input type="checkbox"/>	US 20050025999 A1	20050203	17	Low resistance magnetic tunnel junction structure	428/811.1	324/207.21; 324/249
11	<input type="checkbox"/>	<input type="checkbox"/>	US 20040251232 A1	20041216	54	Method of fabricating a shiftable magnetic shift register	216/22	

Document4 - ... Inbox - Micro... eDAN 1.7 - ... EAST - [108... EAST Brows... E